

2STR2215

Low voltage fast-switching PNP power transistor

Features

- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Miniature SOT-23 plastic package for surface mounting circuits

Applications

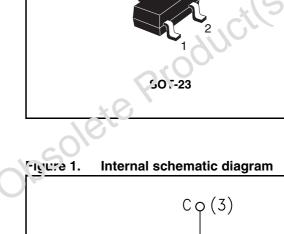
- LED
- Battery charger
- Motor and relay driver
- Voltage regulation

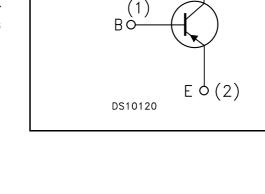
Description

The 2STR2215 is a PNP transistor manufactured using new "PB-HCD" (power bipolar high current density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage. The complementar (NPN is the 2STR1215.



Order code	Marking	Package	Packaging
2STR2215	215	SOT-23	Tape and reel





Electrical ratings 1

Table 2.	Absolute maximum ratings
	Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-15	V
V_{CEO}	Collector-emitter voltage (I _B = 0)	-15	V
V _{EBO}	Emitter-base voltage (I _C = 0)	-5	V
۱ _C	Collector current	-1.5	Α
I _{CM}	Collector peak current (t _P < 5 ms)	-3 6	A
P _{tot}	Total dissipation at T _{amb} = 25 °C	0.5	W
T _{stg}	Storage temperature	- 35 '0 150	°C
Τ _J	Max. operating junction temperature	150	°C
Table 3.	Thermal data		
0		N L	

Thermal data Table 3.

Symbol	Parameter	Value	Unit	
R _{thj-amb} ⁽¹⁾	Thermal resistance junction-amb ma	ax	250	°C/W

area of 1. 1. Device mounted on PCB area of 1cm²



2 Electrical characteristics

(T_{case} = 25 °C unless otherwise specified)

Table 4.	Electrical	characteristics
	Liootiioui	01101 00101 101100

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E =0)	V _{CB} = -15 V			-0.1	μA
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = -4 V			-0.1	μA
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	I _C = -100 μA	-15	40		v
V _{(BR)CEO} ⁽¹⁾	Collector-emitter breakdown voltage $(I_B = 0)$	I _C = -10 mA	-15			V
V _{(BR)EBO}	Emitter-base breakdown voltage $(I_C = 0)$	l _E = -100 μA	-5			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_{C} = -iC0 \text{ mA}$ $I_{B} = -1 \text{ mA}$ $I_{C} = -1 \text{ A}$ $I_{B} = -100 \text{ mA}$ $I_{C} = -2 \text{ A}$ $I_{B} = -200 \text{ mA}$		-0.25 -0.40	-0.15 -0.50 -0.85	V V V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = -1 A I _B = -100 mA		-0.90	-1.25	V
h _{FE} ⁽¹⁾	DC current gain		200 200 130 80	280	560	
C _{CBO}	Collector-base capacitance (I _E = 0)	V _{CB} = -10 V f = 1 MHz		20		pF
t _{on} t _{off}	Resistive load Turn-on time Turn-off time	$I_{C} = -1.5 \text{ A}$ $V_{CC} = -10 \text{ V}$ $I_{B1} = -I_{B2} = -150 \text{ mA}$		60 220		ns ns

1. Pulsed duration = 300 μ s, duty cycle \leq 1.5%



2.1 Electrical characteristics (curves)

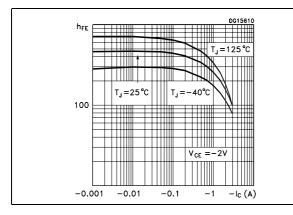
Figure 2. DC current gain

Figure 3. Collector-emitter saturation voltage

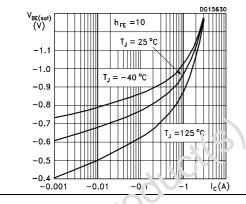
V_{CE (sat)} (V)

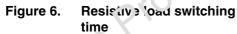
-1

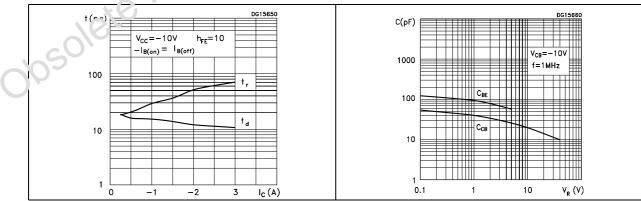
-0.1









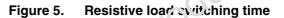


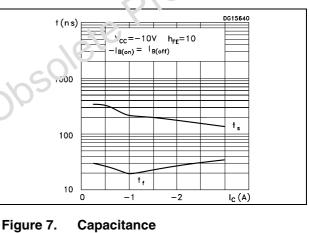
-0.01 -0.1 -0.1 -1 (x)

T_J =−40 °C

T」=25 ℃

 $T_1 = 125$





2.2 Test circuit

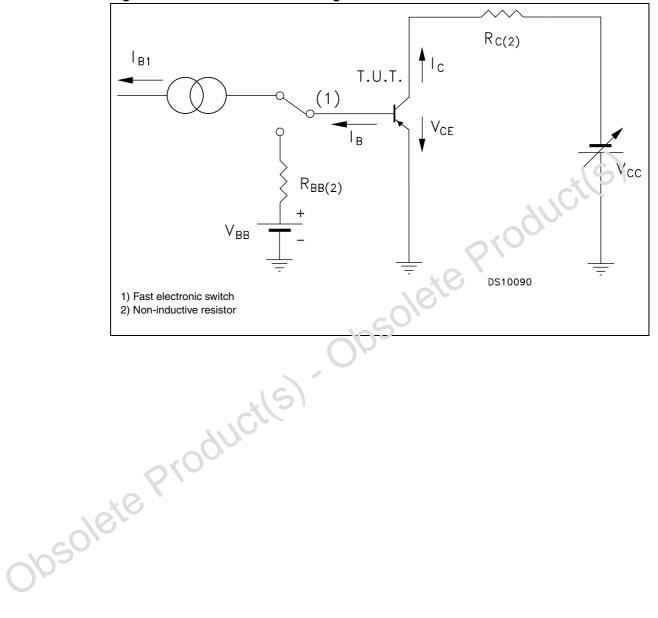


Figure 8. Resistive load switching test circuit



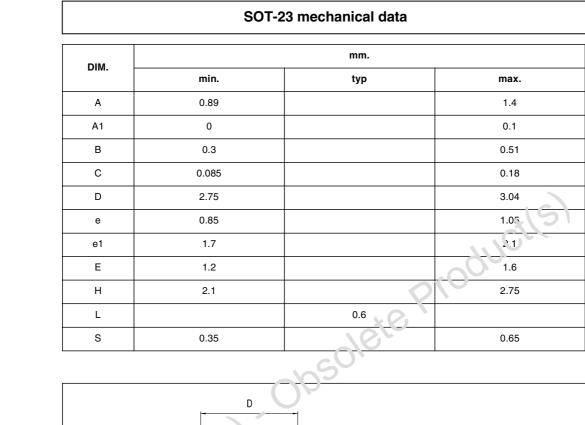
3 Package mechanical data

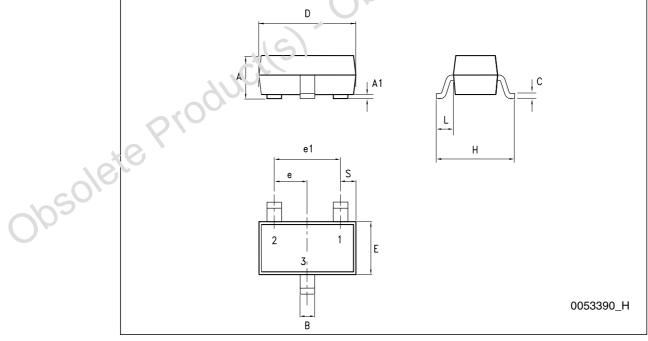
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4 Revision history

Table 5.Document revision history

	Date	Revision	Changes
	09-Feb-2006	1	Initial release.
	20-Jul-2006	2	New template.
	08-Sep-2008	3	Updated the SOT-23 mechanical data.
	08-Jan-2009	4	Updated <i>Figure 1: Internal schematic diagram</i> Updated statement ECOPACK [®]
005018	tepro	ductl	updated statement ECOPACK®



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